

**62 mm C-Series module with TRENCHSTOP™ IGBT7 and emitter controlled 7 diode and pre-applied thermal interface material****Features**

- Electrical features
  - $V_{CES} = 1200\text{ V}$
  - $I_{C\text{ nom}} = 450\text{ A} / I_{CRM} = 900\text{ A}$
  - TRENCHSTOP™ IGBT7
  - $V_{CE,sat}$  with positive temperature coefficient
  - Suitable Infineon gate drivers can be found under <https://www.infineon.com/gdfinder>
- Mechanical features
  - 4 kV AC 1 min insulation
  - High creepage and clearance distances
  - High power density
  - Isolated base plate
  - Package with CTI > 400
  - Standard housing
  - Pre-applied thermal interface material

**Potential applications**

- Servo drives
- Solar applications
- UPS systems
- Motor drives
- High-power converters
- Commercial agriculture vehicles
- Three-level applications

**Product validation**

- Qualified for industrial applications according to the relevant tests of IEC 60747, 60749 and 60068

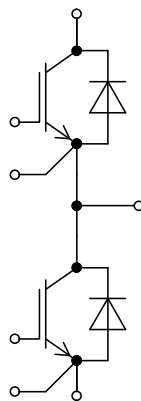
**Description**

Table of contents

|   |                                |    |
|---|--------------------------------|----|
|   | Description .....              | 1  |
|   | Features .....                 | 1  |
|   | Potential applications .....   | 1  |
|   | Product validation .....       | 1  |
|   | Table of contents .....        | 2  |
| 1 | Package .....                  | 3  |
| 2 | IGBT, T1 / T2 .....            | 3  |
| 3 | Diode, D1 / D2 .....           | 5  |
| 4 | Characteristics diagrams ..... | 7  |
| 5 | Circuit diagram .....          | 11 |
| 6 | Package outlines .....         | 12 |
| 7 | Module label code .....        | 13 |
|   | Revision history .....         | 14 |
|   | Disclaimer .....               | 15 |

## 1 Package

**Table 1** Insulation coordination

| Parameter                           | Symbol      | Note or test condition                        | Values    | Unit |
|-------------------------------------|-------------|-----------------------------------------------|-----------|------|
| Isolation test voltage              | $V_{ISOL}$  | RMS, $f = 50 \text{ Hz}$ , $t = 60 \text{ s}$ | 4.0       | kV   |
| Material of module baseplate        |             |                                               | Cu        |      |
| Internal isolation                  |             | basic insulation (class 1, IEC 61140)         | $Al_2O_3$ |      |
| Creepage distance                   | $d_{Creep}$ | terminal to heatsink                          | 29.0      | mm   |
| Creepage distance                   | $d_{Creep}$ | terminal to terminal                          | 23.0      | mm   |
| Clearance                           | $d_{Clear}$ | terminal to heatsink                          | 23.0      | mm   |
| Clearance                           | $d_{Clear}$ | terminal to terminal                          | 11.0      | mm   |
| Comparative tracking index          | $CTI$       |                                               | > 400     |      |
| Relative thermal index (electrical) | $RTI$       | housing                                       | 140       | °C   |

**Table 2** Characteristic values

| Parameter                                | Symbol        | Note or test condition                          |           | Values |      |      | Unit |
|------------------------------------------|---------------|-------------------------------------------------|-----------|--------|------|------|------|
|                                          |               |                                                 |           | Min.   | Typ. | Max. |      |
| Stray inductance module                  | $L_{sCE}$     |                                                 |           |        | 20   |      | nH   |
| Module lead resistance, terminals - chip | $R_{CC'+EE'}$ | $T_H = 25\text{ }^{\circ}\text{C}$ , per switch |           |        | 0.5  |      | mΩ   |
| Storage temperature                      | $T_{stg}$     |                                                 |           | -40    |      | 125  | °C   |
| Maximum baseplate operation temperature  | $T_{BPmax}$   |                                                 |           |        |      | 125  | °C   |
| Mounting torque for module mounting      | $M$           | - Mounting according to valid application note  | M5, Screw | 3      |      | 6    | Nm   |
| Terminal connection torque               | $M$           | - Mounting according to valid application note  | M6, Screw | 2.5    |      | 5    | Nm   |
| Weight                                   | $G$           |                                                 |           |        | 340  |      | g    |

Note: Storage and shipment of modules with TIM => see AN2012-07

## 2 IGBT, T1 / T2

**Table 3** Maximum rated values

| Parameter                 | Symbol    | Note or test condition   | Values | Unit |
|---------------------------|-----------|--------------------------|--------|------|
| Collector-emitter voltage | $V_{CES}$ | $T_{vj} = 25 \text{ °C}$ | 1200   | V    |

(table continues...)

**Table 3** (continued) Maximum rated values

| Parameter                              | Symbol     | Note or test condition              |                                                                             | Values   | Unit |
|----------------------------------------|------------|-------------------------------------|-----------------------------------------------------------------------------|----------|------|
| Continuous DC collector current        | $I_{CDC}$  | $T_{vj\ max} = 175\ ^\circ\text{C}$ | $T_H = 50\ ^\circ\text{C}$                                                  | 450      | A    |
| Maximum RMS module DC-terminal current | $I_{tRMS}$ |                                     | $T_{\text{Terminal}} = 115\ ^\circ\text{C},$<br>$T_C = 90\ ^\circ\text{C}$  | 650      | A    |
|                                        |            |                                     | $T_{\text{Terminal}} = 115\ ^\circ\text{C},$<br>$T_C = 115\ ^\circ\text{C}$ | 600      |      |
| Repetitive peak collector current      | $I_{CRM}$  | $t_p$ limited by $T_{vj\ op}$       |                                                                             | 900      | A    |
| Gate-emitter peak voltage              | $V_{GES}$  |                                     |                                                                             | $\pm 20$ | V    |

**Table 4** Characteristic values

| Parameter                            | Symbol        | Note or test condition                                                                                |                                | Values |       |      | Unit          |
|--------------------------------------|---------------|-------------------------------------------------------------------------------------------------------|--------------------------------|--------|-------|------|---------------|
|                                      |               |                                                                                                       |                                | Min.   | Typ.  | Max. |               |
| Collector-emitter saturation voltage | $V_{CE\ sat}$ | $I_C = 450\ \text{A}, V_{GE} = 15\ \text{V}$                                                          | $T_{vj} = 25\ ^\circ\text{C}$  |        | 1.50  | 1.75 | V             |
|                                      |               |                                                                                                       | $T_{vj} = 125\ ^\circ\text{C}$ |        | 1.65  |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 150\ ^\circ\text{C}$ |        | 1.70  |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 175\ ^\circ\text{C}$ |        | 1.75  |      |               |
| Gate threshold voltage               | $V_{GEth}$    | $I_C = 9\ \text{mA}, V_{CE} = V_{GE}, T_{vj} = 25\ ^\circ\text{C}$                                    |                                | 5.15   | 5.80  | 6.45 | V             |
| Gate charge                          | $Q_G$         | $V_{GE} = \pm 15\ \text{V}, V_{CC} = 600\ \text{V}$                                                   |                                |        | 7.41  |      | $\mu\text{C}$ |
| Internal gate resistor               | $R_{Gint}$    | $T_{vj} = 25\ ^\circ\text{C}$                                                                         |                                |        | 0.7   |      | $\Omega$      |
| Input capacitance                    | $C_{ies}$     | $f = 100\ \text{kHz}, T_{vj} = 25\ ^\circ\text{C}, V_{CE} = 25\ \text{V}, V_{GE} = 0\ \text{V}$       |                                |        | 70.8  |      | nF            |
| Reverse transfer capacitance         | $C_{res}$     | $f = 100\ \text{kHz}, T_{vj} = 25\ ^\circ\text{C}, V_{CE} = 25\ \text{V}, V_{GE} = 0\ \text{V}$       |                                |        | 0.354 |      | nF            |
| Collector-emitter cut-off current    | $I_{CES}$     | $V_{CE} = 1200\ \text{V}, V_{GE} = 0\ \text{V}$                                                       | $T_{vj} = 25\ ^\circ\text{C}$  |        |       | 0.1  | mA            |
| Gate-emitter leakage current         | $I_{GES}$     | $V_{CE} = 0\ \text{V}, V_{GE} = 20\ \text{V}, T_{vj} = 25\ ^\circ\text{C}$                            |                                |        |       | 100  | nA            |
| Turn-on delay time (inductive load)  | $t_{don}$     | $I_C = 450\ \text{A}, V_{CC} = 600\ \text{V},$<br>$V_{GE} = \pm 15\ \text{V}, R_{Gon} = 0.51\ \Omega$ | $T_{vj} = 25\ ^\circ\text{C}$  |        | 0.370 |      | $\mu\text{s}$ |
|                                      |               |                                                                                                       | $T_{vj} = 125\ ^\circ\text{C}$ |        | 0.381 |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 150\ ^\circ\text{C}$ |        | 0.385 |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 175\ ^\circ\text{C}$ |        | 0.389 |      |               |
| Rise time (inductive load)           | $t_r$         | $I_C = 450\ \text{A}, V_{CC} = 600\ \text{V},$<br>$V_{GE} = \pm 15\ \text{V}, R_{Gon} = 0.51\ \Omega$ | $T_{vj} = 25\ ^\circ\text{C}$  |        | 0.043 |      | $\mu\text{s}$ |
|                                      |               |                                                                                                       | $T_{vj} = 125\ ^\circ\text{C}$ |        | 0.049 |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 150\ ^\circ\text{C}$ |        | 0.051 |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 175\ ^\circ\text{C}$ |        | 0.052 |      |               |

(table continues...)

**Table 4** (continued) Characteristic values

| Parameter                                 | Symbol              | Note or test condition                                                                                                                                                                                                              | Values                                                              |       |       | Unit             |
|-------------------------------------------|---------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------|-------|-------|------------------|
|                                           |                     |                                                                                                                                                                                                                                     | Min.                                                                | Typ.  | Max.  |                  |
| Turn-off delay time<br>(inductive load)   | $t_{\text{doff}}$   | $I_C = 450 \text{ A}$ , $V_{CC} = 600 \text{ V}$ ,<br>$V_{GE} = \pm 15 \text{ V}$ , $R_{\text{Goff}} = 1.5 \Omega$                                                                                                                  | $T_{vj} = 25 \text{ }^\circ\text{C}$                                | 0.522 |       | $\mu\text{s}$    |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 125 \text{ }^\circ\text{C}$                               | 0.588 |       |                  |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 150 \text{ }^\circ\text{C}$                               | 0.610 |       |                  |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 175 \text{ }^\circ\text{C}$                               | 0.623 |       |                  |
| Fall time (inductive load)                | $t_f$               | $I_C = 450 \text{ A}$ , $V_{CC} = 600 \text{ V}$ ,<br>$V_{GE} = \pm 15 \text{ V}$ , $R_{\text{Goff}} = 1.5 \Omega$                                                                                                                  | $T_{vj} = 25 \text{ }^\circ\text{C}$                                | 0.124 |       | $\mu\text{s}$    |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 125 \text{ }^\circ\text{C}$                               | 0.263 |       |                  |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 150 \text{ }^\circ\text{C}$                               | 0.307 |       |                  |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 175 \text{ }^\circ\text{C}$                               | 0.351 |       |                  |
| Turn-on energy loss per pulse             | $E_{\text{on}}$     | $I_C = 450 \text{ A}$ , $V_{CC} = 600 \text{ V}$ ,<br>$L_\sigma = 25 \text{ nH}$ , $V_{GE} = \pm 15 \text{ V}$ ,<br>$R_{\text{Gon}} = 0.51 \Omega$ , $di/dt = 6900 \text{ A}/\mu\text{s}$ ( $T_{vj} = 175 \text{ }^\circ\text{C}$ ) | $T_{vj} = 25 \text{ }^\circ\text{C}$                                | 14.1  |       | mJ               |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 125 \text{ }^\circ\text{C}$                               | 22.2  |       |                  |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 150 \text{ }^\circ\text{C}$                               | 25    |       |                  |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 175 \text{ }^\circ\text{C}$                               | 27.7  |       |                  |
| Turn-off energy loss per pulse            | $E_{\text{off}}$    | $I_C = 450 \text{ A}$ , $V_{CC} = 600 \text{ V}$ ,<br>$L_\sigma = 25 \text{ nH}$ , $V_{GE} = \pm 15 \text{ V}$ ,<br>$R_{\text{Goff}} = 1.5 \Omega$ , $dv/dt = 3100 \text{ V}/\mu\text{s}$ ( $T_{vj} = 175 \text{ }^\circ\text{C}$ ) | $T_{vj} = 25 \text{ }^\circ\text{C}$                                | 36.9  |       | mJ               |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 125 \text{ }^\circ\text{C}$                               | 58.9  |       |                  |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 150 \text{ }^\circ\text{C}$                               | 65.6  |       |                  |
|                                           |                     |                                                                                                                                                                                                                                     | $T_{vj} = 175 \text{ }^\circ\text{C}$                               | 72.2  |       |                  |
| SC data                                   | $I_{\text{SC}}$     | $V_{GE} \leq 15 \text{ V}$ , $V_{CC} = 800 \text{ V}$ ,<br>$V_{\text{CEmax}} = V_{\text{CES}} - L_{\text{sCE}} \cdot di/dt$                                                                                                         | $t_p \leq 8 \mu\text{s}$ ,<br>$T_{vj} = 150 \text{ }^\circ\text{C}$ | 1700  |       | A                |
|                                           |                     |                                                                                                                                                                                                                                     | $t_p \leq 6 \mu\text{s}$ ,<br>$T_{vj} = 175 \text{ }^\circ\text{C}$ | 1500  |       |                  |
| Thermal resistance, junction to heat sink | $R_{\text{thJH}}$   | per IGBT, Valid with IFX pre-applied Thermal Interface Material                                                                                                                                                                     |                                                                     |       | 0.123 | K/W              |
| Temperature under switching conditions    | $T_{vj \text{ op}}$ |                                                                                                                                                                                                                                     | -40                                                                 |       | 175   | $^\circ\text{C}$ |

Note:  $T_{vj \text{ op}} > 150 \text{ }^\circ\text{C}$  is only allowed for operation at overload conditions. For detailed specifications please refer to AN 2018-14.

### 3 Diode, D1 / D2

**Table 5** Maximum rated values

| Parameter                       | Symbol           | Note or test condition               | Values | Unit |
|---------------------------------|------------------|--------------------------------------|--------|------|
| Repetitive peak reverse voltage | $V_{\text{RRM}}$ | $T_{vj} = 25 \text{ }^\circ\text{C}$ | 1200   | V    |
| Continuous DC forward current   | $I_F$            |                                      | 450    | A    |

(table continues...)

**Table 5 (continued) Maximum rated values**

| Parameter                       | Symbol    | Note or test condition                   | Values                                | Unit                 |
|---------------------------------|-----------|------------------------------------------|---------------------------------------|----------------------|
| Repetitive peak forward current | $I_{FRM}$ | $t_P = 1 \text{ ms}$                     | 900                                   | A                    |
| $I^2t$ - value                  | $I^2t$    | $t_P = 10 \text{ ms}, V_R = 0 \text{ V}$ | $T_{vj} = 125 \text{ }^\circ\text{C}$ | $\text{A}^2\text{s}$ |
|                                 |           |                                          | $T_{vj} = 175 \text{ }^\circ\text{C}$ |                      |

**Table 6 Characteristic values**

| Parameter                                 | Symbol             | Note or test condition                                                                                                                             | Values                                |      |       | Unit             |
|-------------------------------------------|--------------------|----------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------|------|-------|------------------|
|                                           |                    |                                                                                                                                                    | Min.                                  | Typ. | Max.  |                  |
| Forward voltage                           | $V_F$              | $I_F = 450 \text{ A}, V_{GE} = 0 \text{ V}$                                                                                                        | $T_{vj} = 25 \text{ }^\circ\text{C}$  | 1.80 | 2.10  | V                |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 125 \text{ }^\circ\text{C}$ | 1.70 |       |                  |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 150 \text{ }^\circ\text{C}$ | 1.65 |       |                  |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 175 \text{ }^\circ\text{C}$ | 1.60 |       |                  |
| Peak reverse recovery current             | $I_{RM}$           | $V_{CC} = 600 \text{ V}, I_F = 450 \text{ A}, V_{GE} = -15 \text{ V}, -di_F/dt = 6900 \text{ A}/\mu\text{s} (T_{vj} = 175 \text{ }^\circ\text{C})$ | $T_{vj} = 25 \text{ }^\circ\text{C}$  | 377  |       | A                |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 125 \text{ }^\circ\text{C}$ | 480  |       |                  |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 150 \text{ }^\circ\text{C}$ | 509  |       |                  |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 175 \text{ }^\circ\text{C}$ | 538  |       |                  |
| Recovered charge                          | $Q_r$              | $V_{CC} = 600 \text{ V}, I_F = 450 \text{ A}, V_{GE} = -15 \text{ V}, -di_F/dt = 6900 \text{ A}/\mu\text{s} (T_{vj} = 175 \text{ }^\circ\text{C})$ | $T_{vj} = 25 \text{ }^\circ\text{C}$  | 39.2 |       | $\mu\text{C}$    |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 125 \text{ }^\circ\text{C}$ | 65.6 |       |                  |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 150 \text{ }^\circ\text{C}$ | 76.4 |       |                  |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 175 \text{ }^\circ\text{C}$ | 87.2 |       |                  |
| Reverse recovery energy                   | $E_{rec}$          | $V_{CC} = 600 \text{ V}, I_F = 450 \text{ A}, V_{GE} = -15 \text{ V}, -di_F/dt = 6900 \text{ A}/\mu\text{s} (T_{vj} = 175 \text{ }^\circ\text{C})$ | $T_{vj} = 25 \text{ }^\circ\text{C}$  | 18   |       | mJ               |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 125 \text{ }^\circ\text{C}$ | 32.8 |       |                  |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 150 \text{ }^\circ\text{C}$ | 37.4 |       |                  |
|                                           |                    |                                                                                                                                                    | $T_{vj} = 175 \text{ }^\circ\text{C}$ | 41.9 |       |                  |
| Thermal resistance, junction to heat sink | $R_{thJH}$         | per diode, Valid with IFX pre-applied Thermal Interface Material                                                                                   |                                       |      | 0.186 | K/W              |
| Temperature under switching conditions    | $T_{vj\text{ op}}$ |                                                                                                                                                    | -40                                   |      | 175   | $^\circ\text{C}$ |

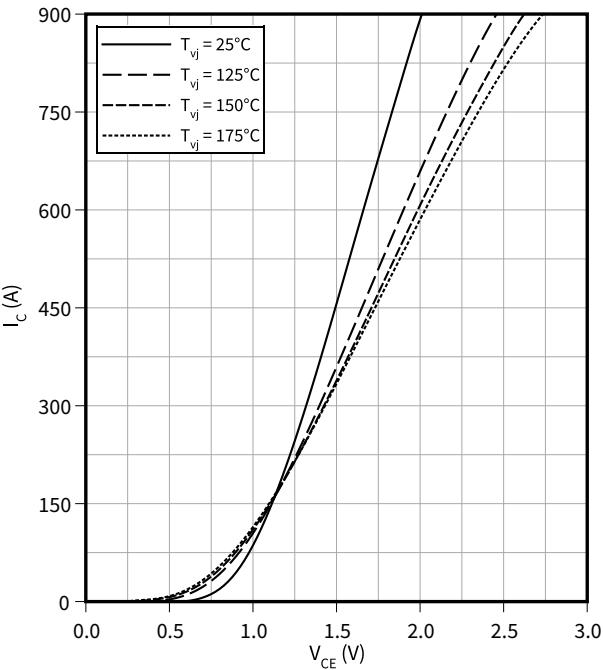
Note:  $T_{vj\text{ op}} > 150 \text{ }^\circ\text{C}$  is only allowed for operation at overload conditions. For detailed specifications please refer to AN 2018-14.

4 Characteristics diagrams

Output characteristic (typical), IGBT, T1 / T2

$I_C = f(V_{CE})$

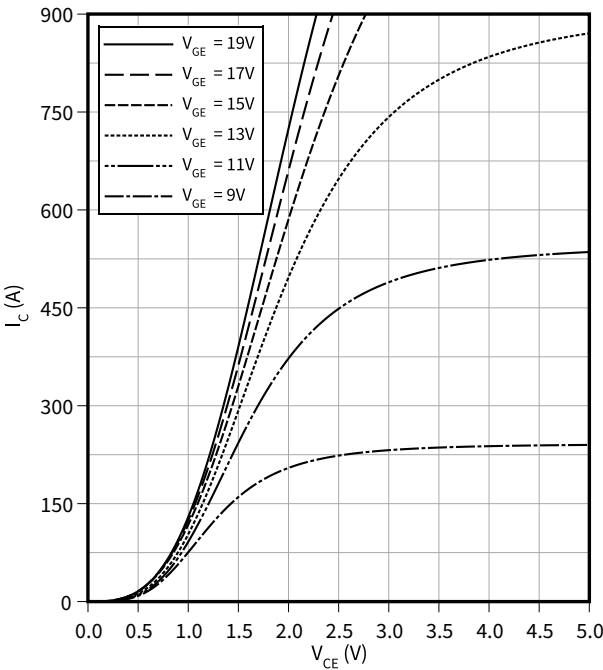
$V_{GE} = 15\text{ V}$



Output characteristic field (typical), IGBT, T1 / T2

$I_C = f(V_{CE})$

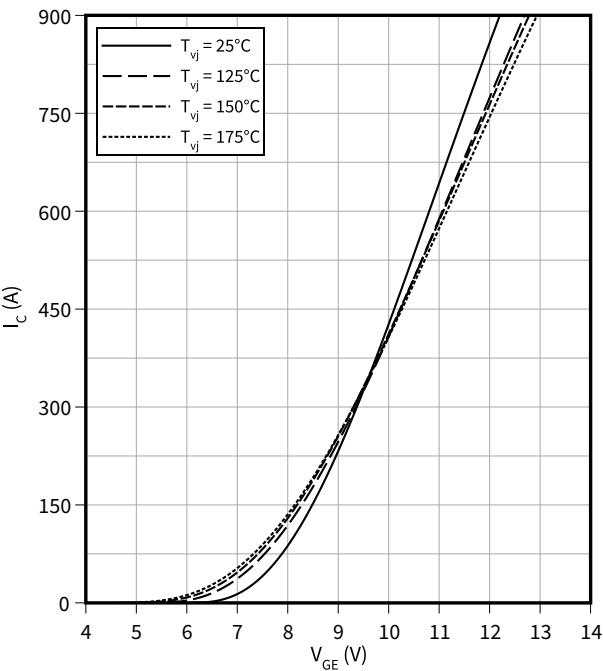
$T_{vj} = 175^\circ\text{C}$



Transfer characteristic (typical), IGBT, T1 / T2

$I_C = f(V_{GE})$

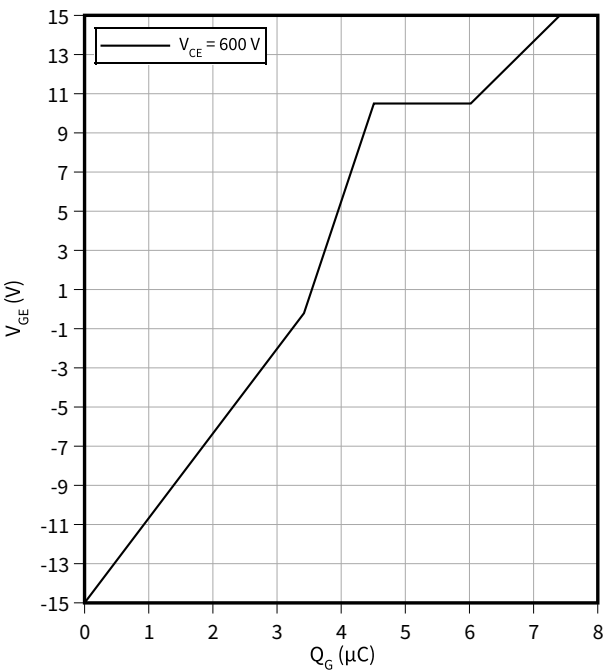
$V_{CE} = 20\text{ V}$



Gate charge characteristic (typical), IGBT, T1 / T2

$V_{GE} = f(Q_G)$

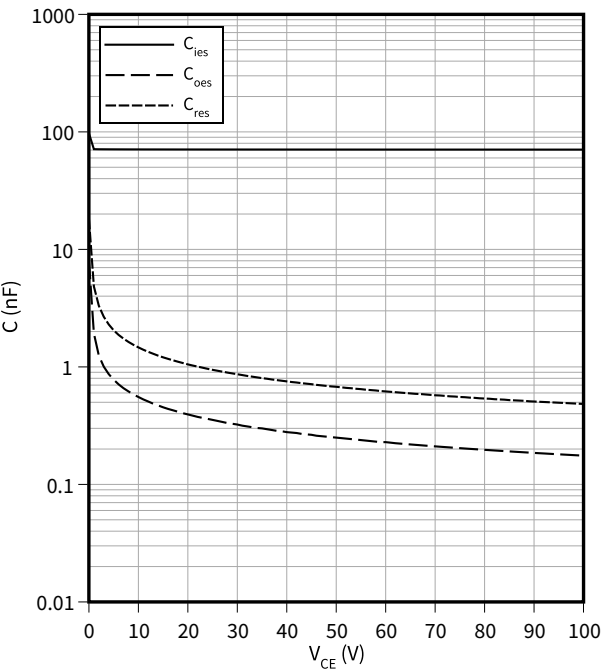
$I_C = 450\text{ A}, T_{vj} = 25^\circ\text{C}$



4 Characteristics diagrams

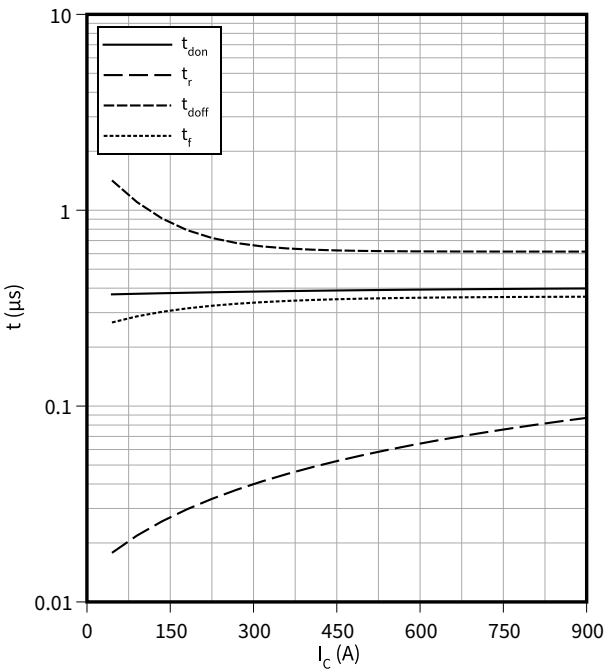
Capacity characteristic (typical), IGBT, T1 / T2

$C = f(V_{CE})$   
 $f = 100 \text{ kHz}$ ,  $V_{GE} = 0 \text{ V}$ ,  $T_{vj} = 25 \text{ }^{\circ}\text{C}$



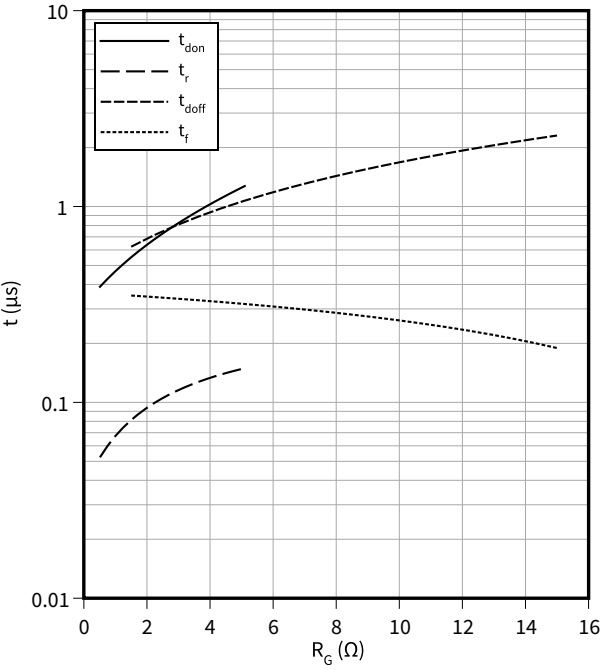
Switching times (typical), IGBT, T1 / T2

$t = f(I_C)$   
 $R_{Goff} = 1.5 \text{ } \Omega$ ,  $R_{Gon} = 0.51 \text{ } \Omega$ ,  $V_{CC} = 600 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$ ,  $T_{vj} = 175 \text{ }^{\circ}\text{C}$



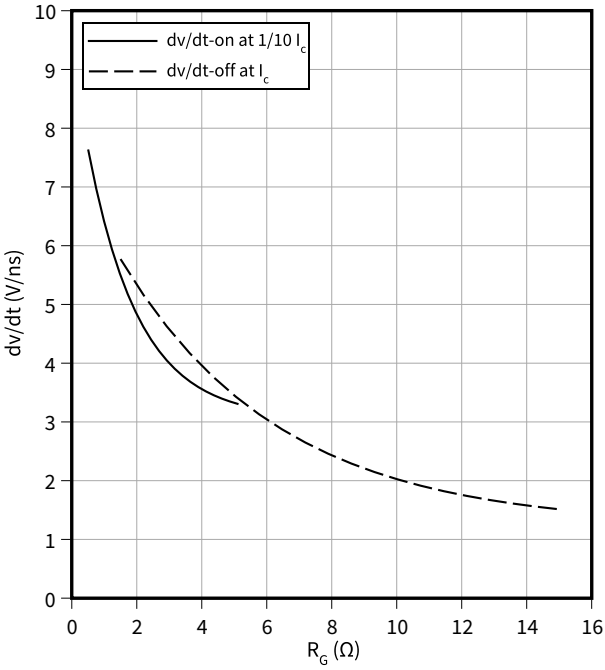
Switching times (typical), IGBT, T1 / T2

$t = f(R_G)$   
 $I_C = 450 \text{ A}$ ,  $V_{CC} = 600 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$ ,  $T_{vj} = 175 \text{ }^{\circ}\text{C}$



Voltage slope (typical), IGBT, T1 / T2

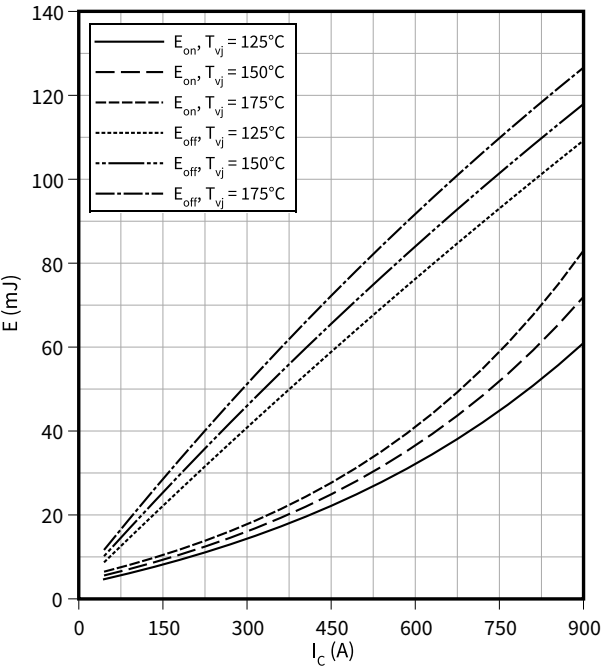
$dv/dt = f(R_G)$   
 $I_C = 450 \text{ A}$ ,  $V_{CC} = 600 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$ ,  $T_{vj} = 25 \text{ }^{\circ}\text{C}$



4 Characteristics diagrams

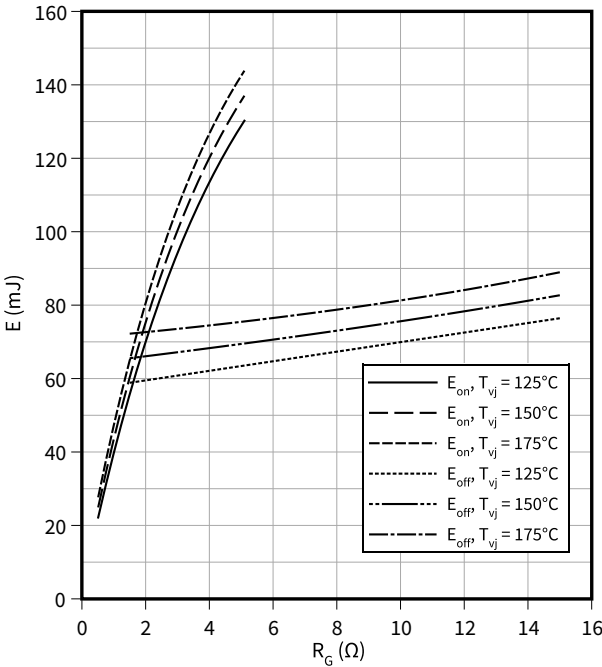
Switching losses (typical), IGBT, T1 / T2

$E = f(I_C)$   
 $R_{Goff} = 1.5 \Omega$ ,  $R_{Gon} = 0.51 \Omega$ ,  $V_{CC} = 600 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$



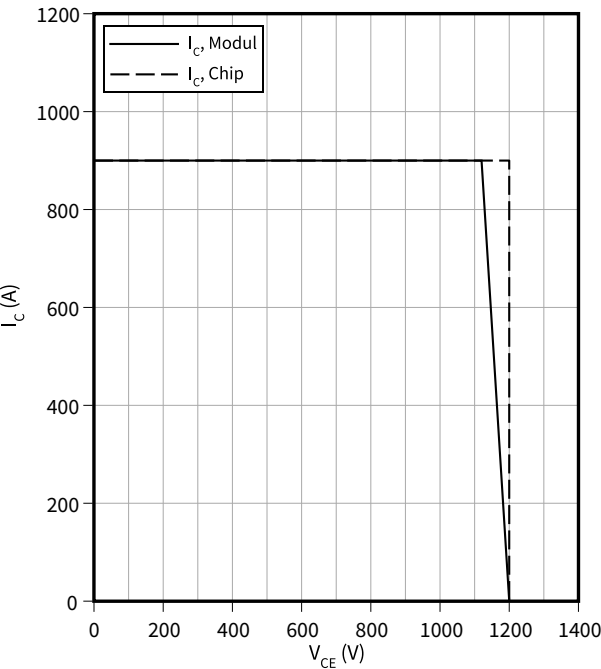
Switching losses (typical), IGBT, T1 / T2

$E = f(R_G)$   
 $I_C = 450 \text{ A}$ ,  $V_{CC} = 600 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$



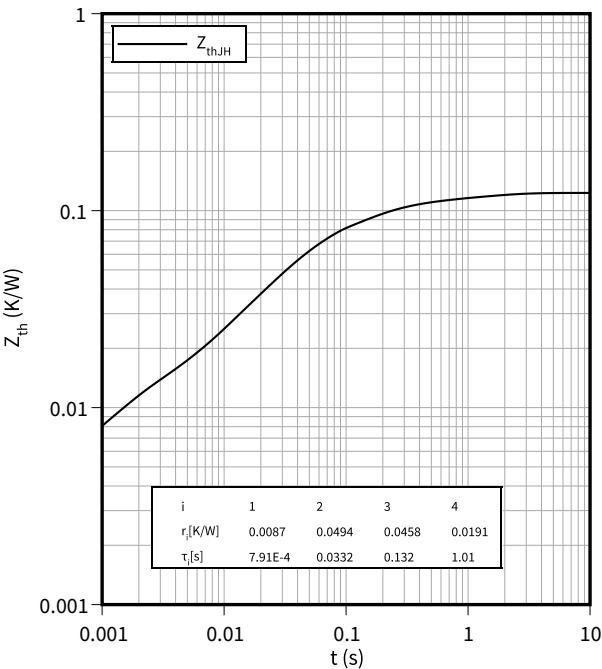
Reverse bias safe operating area (RBSOA), IGBT, T1 / T2

$I_C = f(V_{CE})$   
 $R_{Goff} = 1.5 \Omega$ ,  $V_{GE} = \pm 15 \text{ V}$ ,  $T_{vj} = 175 \text{ °C}$



Transient thermal impedance, IGBT, T1 / T2

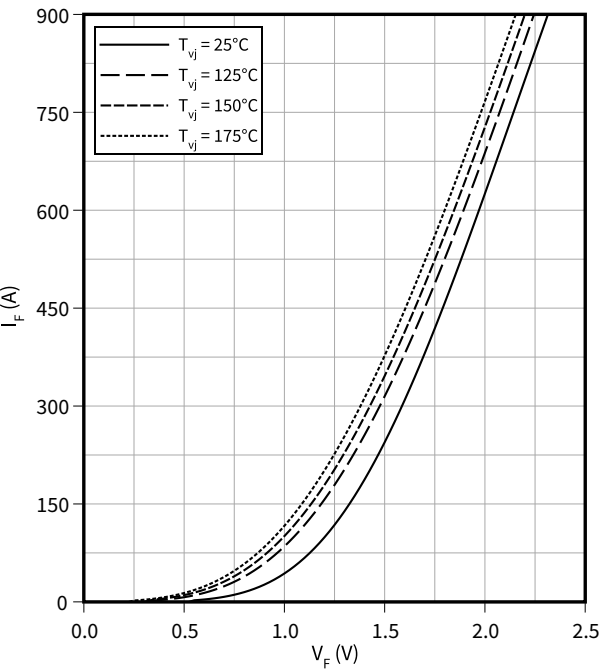
$Z_{th} = f(t)$



4 Characteristics diagrams

Forward characteristic (typical), Diode, D1 / D2

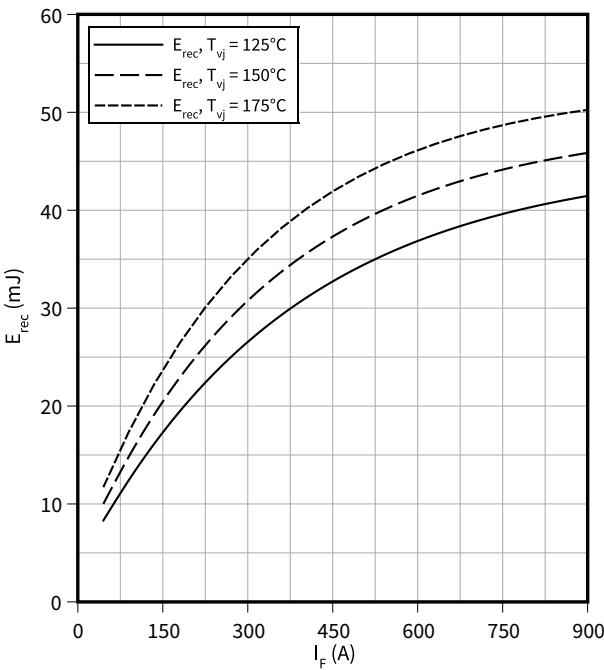
$I_F = f(V_F)$



Switching losses (typical), Diode, D1 / D2

$E_{rec} = f(I_F)$

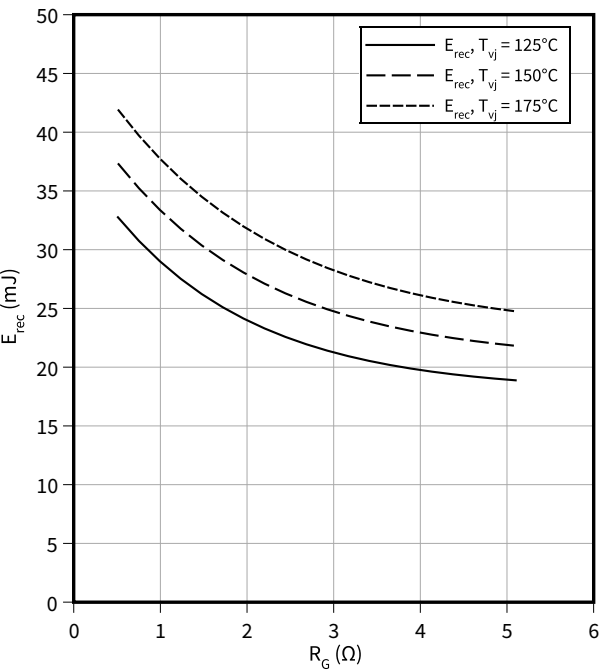
$R_{Gon} = 0.51 \, \Omega, V_{CE} = 600 \, V$



Switching losses (typical), Diode, D1 / D2

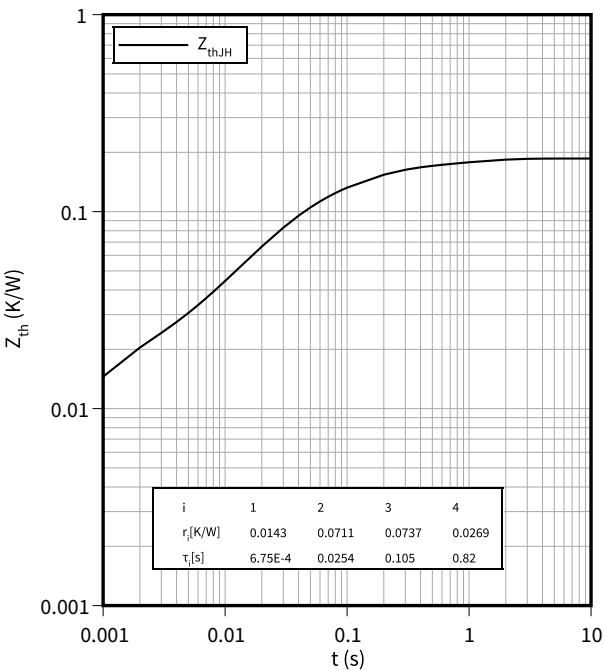
$E_{rec} = f(R_G)$

$V_{CE} = 600 \, V, I_F = 450 \, A$

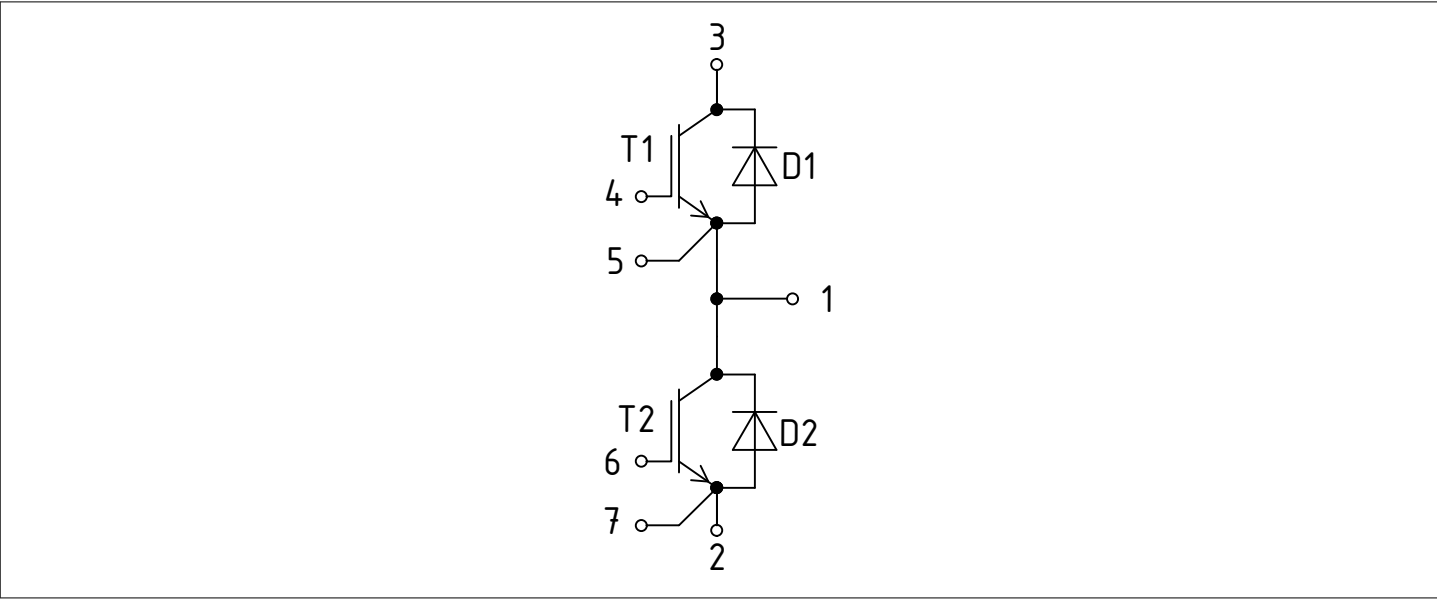


Transient thermal impedance, Diode, D1 / D2

$Z_{th} = f(t)$

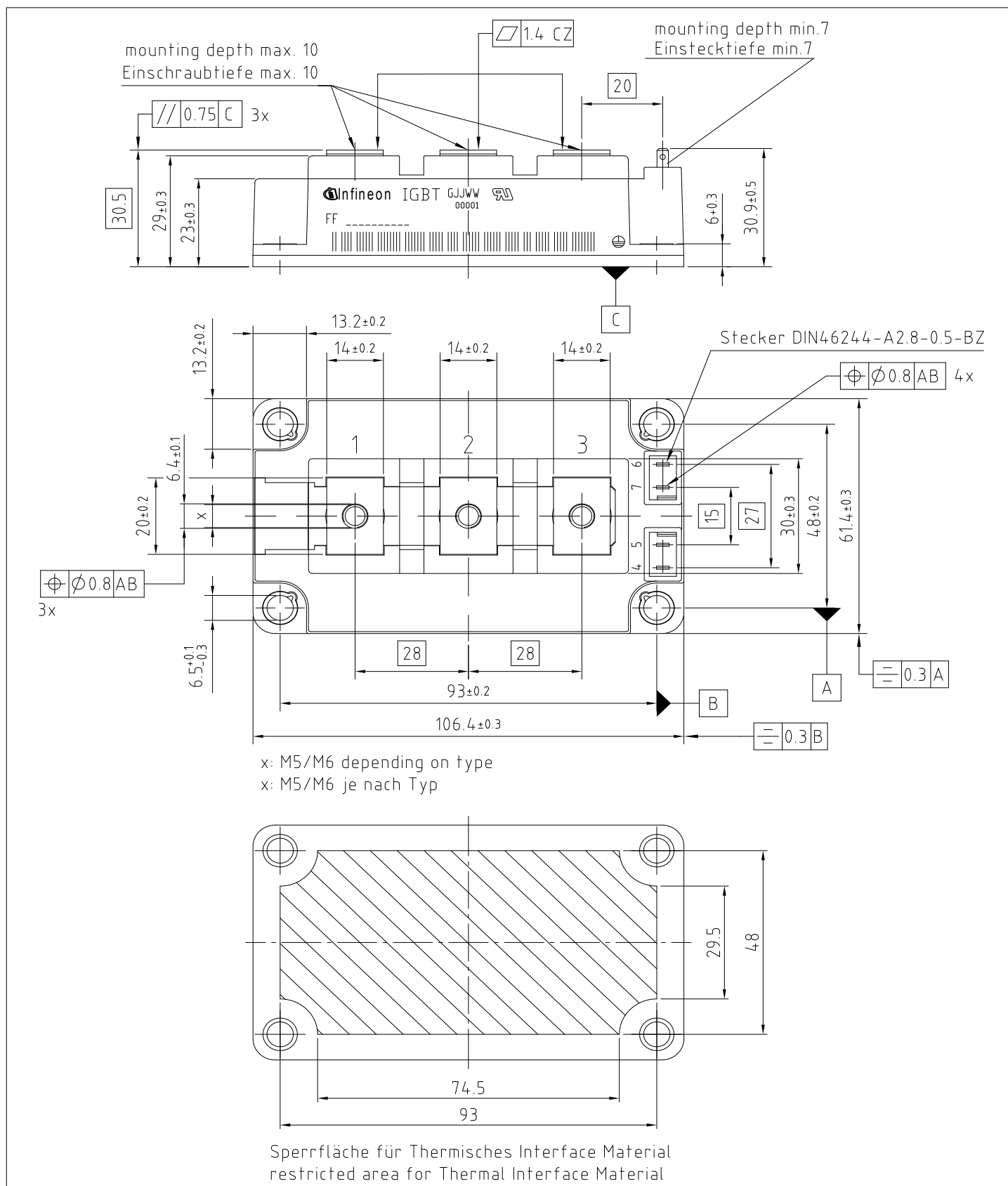


5      **Circuit diagram**



**Figure 1**

## 6 Package outlines



**Figure 2**

7 Module label code

| Module label code       |                                                                                     |                         |                 |
|-------------------------|-------------------------------------------------------------------------------------|-------------------------|-----------------|
| Code format             | Data Matrix                                                                         |                         | Barcode Code128 |
| Encoding                | ASCII text                                                                          |                         | Code Set A      |
| Symbol size             | 16x16                                                                               |                         | 23 digits       |
| Standard                | IEC24720 and IEC16022                                                               |                         | IEC8859-1       |
| Code content            | <i>Content</i>                                                                      | <i>Digit</i>            | <i>Example</i>  |
|                         | Module serial number                                                                | 1 – 5                   | 71549           |
|                         | Module material number                                                              | 6 - 11                  | 142846          |
|                         | Production order number                                                             | 12 - 19                 | 55054991        |
|                         | Date code (production year)                                                         | 20 – 21                 | 15              |
|                         | Date code (production week)                                                         | 22 – 23                 | 30              |
| Example                 |   |                         |                 |
|                         |  |                         |                 |
| 71549142846550549911530 |                                                                                     | 71549142846550549911530 |                 |

Figure 3



Revision history

Revision history

| Document revision | Date of release | Description of changes |
|-------------------|-----------------|------------------------|
| 1.00              | 2023-07-14      | Initial version        |

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